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FDD6296/FDU6296

30V N-Channel Fast Switching PowerTrench^o MOSFET

General Description

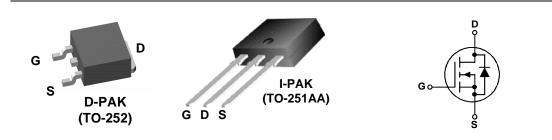
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

Applications

- DC/DC converter
- Power management

Features

- 50A, 30 V $\begin{array}{c} R_{DS(ON)} = 8.8 \ m\Omega \ @ \ V_{GS} = 10 \ V \\ R_{DS(ON)} = 11.3 \ m\Omega \ @ \ V_{GS} = 4.5 \ V \end{array}$
- Low gate charge
- Fast switching
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$



Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	F	Parameter		Ratings		Units	
V _{DSS}	Drain-Source Voltage				V		
V _{GSS}	Gate-Source Voltage						
I _D	Continuous Drain Current @T _C =25°C		C (Note 3)		50		
		@T _A =25°	C (Note 1a)		15		
		Pulsed	(Note 1a)		100		
P _D	Power Dissipation @T _c		C (Note 3)		52	W	
		@T _A =25°	C (Note 1a)	3.8			
		@T _A =25°	C (Note 1b)		1.6		
T _J , T _{STG}	Operating and Storag	ge Junction Terr	perature Range	-55 to +175		°C	
Therma	l Characteristi	CS					
R _{eJC}	Thermal Resistance,	Junction-to-Cas	Se (Note 1)	2.9		°C/W	
R _{0JA}	Thermal Resistance, Junction-to-Ambient (Note 1a)						
	Thermal Resistance,	Junction-to-Am					
Packag	e Marking and	Ordering	Informatior	1		·	
Device		evice	Package	Reel Size	Tape width	Quantity	
FDD	6296 FD	D6296 [D-PAK (TO-252)	-PAK (TO-252) 13'' 16mm		2500 units	
FDU	6296 FD	U2696	I-PAK (TO-251)	Tube	N/A	75	

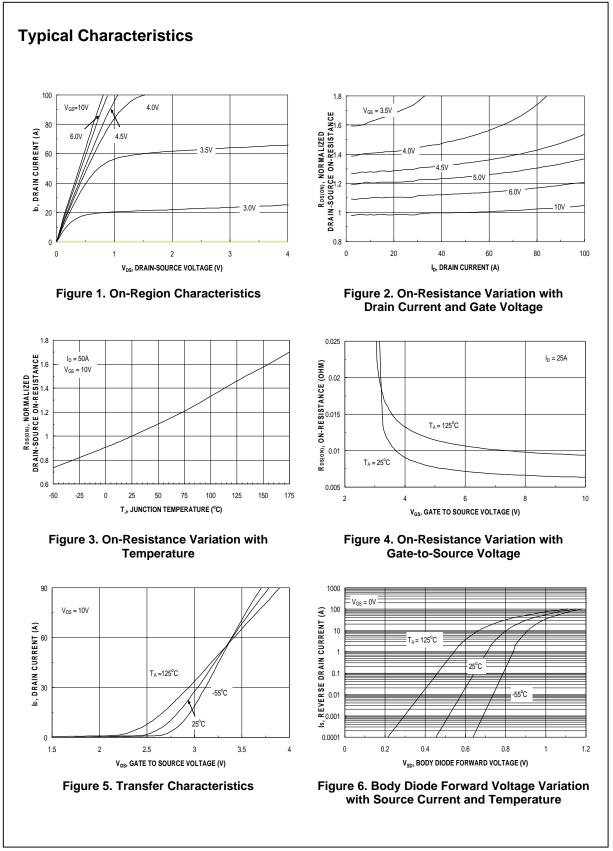
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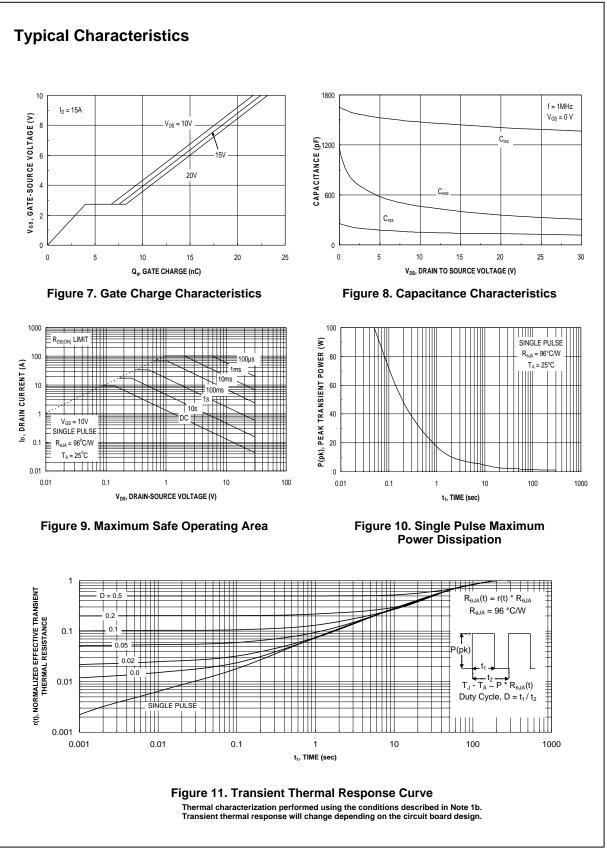
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	urce Avalanche Ratings (Note	I ∋ 2)				
E _{AS}	Drain-Source Avalanche Energy	Single Pulse, $V_{DD} = 15 \text{ V}$, $I_D = 15 \text{ A}$			165	mJ
I _{AS}	Drain-Source Avalanche Current				15	А
Off Chara	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	30			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 µA, Referenced to 25°C		29		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, \qquad V_{GS} = 0 \text{ V}$			1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			± 100	nA
On Chara	Acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = 250 \ \mu A$	1	1.7	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-0.5		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{GS} = 10 \ V, & I_D = 15 \ A \\ V_{GS} = 4.5 \ V, & I_D = 13 \ A \\ V_{GS} = 10 \ V, & I_D = 15 \ A, \ T_J = 125^\circ C \end{array} $		7.5 9.0 9.3	8.8 11.3 15.0	mΩ
g _{FS}	Forward Transconductance	$V_{DS} = 5 V$, $I_D = 15 A$		58		S
Dynamic	Characteristics		•			
C _{iss}	Input Capacitance	$V_{DS} = 15 \text{ V}, \qquad V_{GS} = 0 \text{ V},$		1440		pF
Coss	Output Capacitance	f = 1.0 MHz		400		pF
C _{rss}	Reverse Transfer Capacitance			140		pF
R _G	Gate Resistance	$V_{GS} = 15 \text{ mV}, f = 1.0 \text{ MHz}$		1.3		Ω
Switching	Characteristics (Note 2)		•			
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 15 V$, $I_D = 1 A$,		11	19	ns
t _r	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		6	11	ns
t _{d(off)}	Turn-Off Delay Time			29	46	ns
t _f	Turn–Off Fall Time			13	23	ns
Qg	Total Gate Charge	$V_{DS} = 15V, I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}$		22.5	31.5	nC
Qg	Total Gate Charge	$V_{DS} = 15V,$ $I_{D} = 15 A,$		12.2	17	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 5 V$		4		nC
Q _{gd}	Gate–Drain Charge			3.5		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain–Source	ce Diode Forward Current			3.2	А
V _{SD}	Drain–Source Diode Forward Voltage	$V_{\text{GS}} = 0 \ \text{V}, I_{\text{S}} = 3.2 \ \text{A} \qquad (\text{Note 2})$		0.74	1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_{F} = 15 A,$		25		nS
Q _{rr}	Diode Reverse Recovery Charge	$d_{iF}/d_t = 100 \text{ A/}\mu\text{s}$		13		nC

Electrical Characteristics (cont'd)					
Notes: 1. R _{8JA} is the sum of the junction-to-cas the drain pins. R _{8JC} is guaranteed by	se and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of y design while R _{9CA} is determined by the user's board design.	FDD6296/FDU6296			
	 a) R_{0JA} = 40°C/W when mounted on a 1in² pad of 2 oz copper b) R_{0JA} = 96°C/W when mounted on a minimum pad. 	U6296			
2. Pulse Test: Pulse Width < 300μs, Du	Scale 1 : 1 on letter size paper				
 a. Maximum current is calculated as: current limitation is 21A 	$\sqrt{\frac{P_{D}}{R_{DS(ON)}}}$ where P _D is maximum power dissipation at T _C = 25°C and R _{DS(on)} is at T _{J(max)} and V _{GS} = 10V. Package	Э			
	FDD6296/FDU6296 Rev. 2.				



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FDD6296/FDU6296 Rev. 2.1



FDD6296/FDU6296

FDD6296/FDU6296 Rev. 2.1



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